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_	APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
	10/737,393	12/16/2003	Kenichi Morimoto	A-468	5877
	802 7	10/03/2006		EXAMINER	
	PATENTTM.US			OLSEN, ALLAN W	
	P. O. BOX 827 PORTLAND.	788 OR 97282-0788		ART UNIT	PAPER NUMBER
	,			1763	
				DATE MAILED: 10/03/200	6

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)					
	10/737,393	MORIMOTO, KENICHI					
Office Action Summary	Examiner	Art Unit					
. ·	Allan Olsen	1763					
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with the	e correspondence address					
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1)⊠ Responsive to communication(s) filed on 14 J	lune 2006						
•	s action is non-final.						
· · · · · · · · · · · · · · · · · · ·		prosecution as to the merits is					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
	ex parto Quayro, 1000 0.5. 11,						
Disposition of Claims							
4) Claim(s) 1-4 and 10 is/are pending in the applications	4)⊠ Claim(s) <u>1-4 and 10</u> is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
Claim(s) <u>1-4 and 10</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/o	or election requirement.	·					
Application Papers							
9)☐ The specification is objected to by the Examiner.							
0)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
Applicant may not request that any objection to the	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign	n priority under 35 H S C & 110	(a)-(d) or (f)					
a) ☐ All b) ☐ Some * c) ☐ None of:	T priority under 55 5.5.5. § 115	(a)-(a) or (i).					
1.☐ Certified copies of the priority documen	ts have been received						
2. Certified copies of the priority documen		ation No					
3. Copies of the certified copies of the prior	• •						
application from the International Burea	- \ <del>'</del>						
* See the attached detailed Office action for a list		ived.					
	. s. are continue copied net rece						
· •							
Attachment(s)	_						
) Notice of References Cited (PTO-892)  4) Interview Summary (PTO-413)  Paper No(s)/Mail Date							
Notice of Draftsperson's Patent Drawing Review (PTO-948)  □ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)  □ Notice of Informal Patent Application (PTO-152)							
Paper No(s)/Mail Date	6) Other:						
	<del></del>	<u> </u>					

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### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

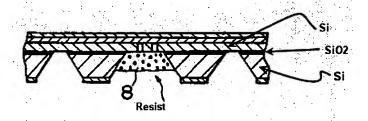
The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims is rejected under 35 U.S.C. 102(b) as being anticipated by US Patent 5,756,237 issued to Amemiya.

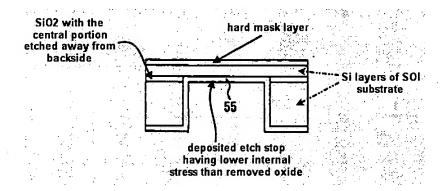
As shown by the following annotated version of Amemiya's Figure 10D, Amemiya teaches a structure that corresponds the mask blank of claim 1. See also column 13, lines 1-30.



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Claims 1-4 and 10 are rejected under 35 U.S.C. 102(b) as being anticipated by EP 1 065 566 issued to Hoya Corporation (hereinafter, Hoya).

As shown by the following annotation of figure 15E, Hoya teaches a structure that corresponds the mask blank of claim 1.



Hoya teaches that the hard mask layer and the etch stop may be TiN. In the following excerpt, the "electron beam scattering body" and the "pattern supporting layer" correspond to the hard mask layer and the deposited etch stop, respectively. As Hoya teaches using the same material that is claimed by applicant, the magnitude of internal stress are expected to be the same.

[0246] Although the present invention has been described by enumerating its several embodiments, it should not be limited to the scopes of the invention. In the Embodiments 1 to 8, for example, the step order should not be especially ilmited if it can satisfy the mask structure of the final target. On the other hand, the etching mask may be made of any material including an organic material such as a resist, an inorganic material such as SiO<sub>2</sub> or a metallic material.

[0247] Moreover, the electron beam scattering body material or the pattern supporting layer material may be any if it satisfies the mask characteristics of the present invention. This material can be exemplified by not only the aforementioned ones but also a chemical semiconductor material such as boron nitride (BNx), carbon nitride (CNx), titanium nitride (TiNx), inclum phosphide (InP) or gaillum nitride (GaNx). In addition, there can be used any material including a silicide such as titanium silicide (TiSix), a carbide such as titanium carbide (TiC) or a boride such as B-doped Si (111) or TiBx, if it satisfies the required characteristics such as the chemical resistance, the etching workability or the film forming property. The etching stopper layer can be exemplified by not only the aforementioned ones but also Si, Ti, TiCNx or TiSix.

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### Response to Arguments

Applicant's arguments with respect to claims have been considered but are moot in view of the new grounds of rejection.

#### Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Note: figure 36C in US 2004/0087065; figure 2G in US 2004/0055401; figure 15E in US 7,060,996.

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Allan Olsen whose telephone number is 571-272-1441. The examiner can normally be reached on M, W and F: 1-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on 571-272-1435. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Allan Olsen
Primary Examiner
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